RF TEST REPORT

Applicant	Quectel Wireless Solutions Co., Ltd.
FCC ID	XMR201707BG96
Product	LTE Cat M1 & Cat NB1 & EGPRS Module
Brand	Quectel
Model	BG96, BG96 MINIPCIE
Marketing	Quectel BG96, Quectel BG96 MINIPCIE
Report No.	R1811A0536-R3
Issue Date	February 26, 2019

TA Technology (Shanghai) Co., Ltd. tested the above equipment in accordance with the requirements in **FCC CFR47 Part 2 (2018)/ FCC CFR47 Part 27C (2018)**. The test results show that the equipment tested is capable of demonstrating compliance with the requirements as documented in this report.

Peng Tao

Performed by: Peng Tao

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Summary of Measurement Results

Number	Test Case	Clause in FCC rules	Verdict
1	RF power output	2.1046	PASS
2	Effective Isotropic Radiated power	27.50(d)(4) /27.50(b)(10) /27.50(c)(10)	PASS
3	Occupied Bandwidth	2.1049	PASS
4	Band Edge Compliance	27.53(h) /27.53(g)	PASS
5	Peak-to-Average Power Ratio	27.50(d)/KDB971168 D01(5.7)	PASS
6	Frequency Stability	2.1055 / 27.54	PASS
7	Spurious Emissions at Antenna Terminals	2.1051 /27.53(h) /27.53(g) /27.53(f)	PASS
8	Radiates Spurious Emission	2.1053 /27.53(h) /27.53(g) /27.53(f)	PASS
Date of Testing: June 24, 2017~ July 3, 2017			
Note: PASS: The EUT complies with the essential requirements in the standard. FAIL: The EUT does not comply with the essential requirements in the standard.			

BG96, BG96 MINIPCIE (Report No: R1811A0536-R3) is a variant model of BG96 (Report No: RXA1706-0199RF03R1). The detailed product change description please refers to the ANNEX B.

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1 Test Laboratory

1.1 Notes of the Test Report

This report shall not be reproduced in full or partial, without the written approval of **TA technology (shanghai) co., Ltd.** The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein .Measurement Uncertainties were not taken into account and are published for informational purposes only. This report is written to support regulatory compliance of the applicable standards stated above. This report must not be used by the client to claim product certification, approval, or endorsement by any government agencies.

1.2 Test facility

CNAS (accreditation number: L2264)

TA Technology (Shanghai) Co., Ltd. has obtained the accreditation of China National Accreditation Service for Conformity Assessment (CNAS).

FCC (recognition number is 428261)

TA Technology (Shanghai) Co., Ltd. has been listed on the US Federal Communications Commission list of test facilities recognized to perform electromagnetic emissions measurements.

IC (recognition number is 8510A)

TA Technology (Shanghai) Co., Ltd. has been listed by industry Canada to perform electromagnetic emission measurement.

VCCI (recognition number is C-4595, T-2154, R-4113, G-10766)

TA Technology (Shanghai) Co., Ltd. has been listed by industry Japan to perform electromagnetic emission measurement.

A2LA (Certificate Number: 3857.01)

TA Technology (Shanghai) Co., Ltd. has been listed by American Association for Laboratory Accreditation to perform electromagnetic emission measurement.

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1.3 Testing Location

Company:	TA Technology (Shanghai) Co., Ltd.
Address:	No.145, Jintang Rd, Tangzhen Industry Park, Pudong Shanghai, China
City:	Shanghai
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2 General Description of Equipment under Test

Client Information

Applicant	Quectel Wireless Solutions Co., Ltd.
Applicant address	7th Floor, Hongye Building, No. 1801 Hongmei Road, Xuhui District, Shanghai, China
Manufacturer	Quectel Wireless Solutions Co., Ltd.
Manufacturer address	7th Floor, Hongye Building, No. 1801 Hongmei Road, Xuhui District, Shanghai, China

General information

EUT Description			
Model:	BG96, BG96 MINIPCIE		
IMEI:	866425038291656		
Hardware Version:	R1.2		
Software Version:	BG96MAR04A01M1G		
Power Supply:	External power supply		
Antenna Type:	The EUT don't have standard Antenna, The Antenna used for testing in this report is the after-market accessory (Dipole Antenna)		
Test Mode(s):	LTE Band 4; LTE Band 12, LTE Band 13;		
Test Modulation	QPSK 16QAM;		
LTE Category	M1		
Maximum E.I.R.P./ E.R.P.	LTE Band 4:	29.98dBm	
	LTE Band 12:	27.79dBm	
	LTE Band 13:	27.17dBm	
Rated Power Supply Voltage:	3.8V		
Extreme Voltage:	Minimum: 3.3V Maximum: 4.3V		
Extreme Temperature:	Lowest: -40°C Highest: +85°C		
Operating Frequency Range(s)	Mode	Tx (MHz)	Rx (MHz)
	LTE Band 4	1710 ~ 1755	2110 ~ 2155
	LTE Band 12	699 ~ 716	729 ~ 746
	LTE Band 13	777 ~ 787	746 ~ 756
Note：1. The information of the EUT is declared by the manufacturer.			

The series model number is: BG96 MINIPCIE. The difference of these models are have different marketing requirement.

Accessory equipment	
Evaluation Board	RF Cable
RS232-to-USB Cable	Antenna: Dipole Antenna
Headset	USB Cable

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3 Applied Standards

According to the specifications of the manufacturer, it must comply with the requirements of the following standards:

Test standards

FCC CFR47 Part 2 (2018)

FCC CFR47 Part 27C (2018)

ANSI C63.26 (2015)

KDB 971168 D01 Power Meas License Digital Systems v03r01

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4 Test Configuration

Radiated measurements are performed by rotating the EUT in three different orthogonal test planes. EUT lie-down stand-up position (X, Y axis)，lie-down position (Z axis),. Receiver antenna polarization (horizontal and vertical), the worst emission was found in position (Z axis, vertical polarization) and the worst case was recorded.

All mode and data rates and positions and RB size and modulations were investigated.
Subsequently, only the worst case emissions are reported.
The following testing in LTE is set based on the maximum RF Output Power.
The following testing in different Bandwidth is set to detailin the following table:
Test modes are chosen to be reported as the worst case configuration below for LTE Band 4/12/13:

Test items	Modes	Bandwidth (MHz)						Modulation		RB			Test Channel		
		1.4	3	5	10	15	20	QPSK	16QAM	1	50%	100%	L	M	H
RF power output	LTE 4	O	O	O	O	O	O	O	O	O	O	O	O	O	O
	LTE 12	O	O	O	O	-	-	O	O	O	O	O	O	O	O
	LTE 13	-	-	O	O	-	-	O	O	O	O	O	O	O	O
Effective Isotropic Radiated power	LTE 4	O	O	O	O	O	O	O	O	-	-	O	O	O	O
	LTE 12	O	O	O	O	-	-	O	O	-	-	O	O	O	O
	LTE 13	-	-	O	O	-	-	O	O	-	-	O	O	O	O
Occupied Bandwidth	LTE 4	O	O	O	O	O	O	O	O	-	-	O	-	O	-
	LTE 12	O	O	O	O	-	-	O	O	-	-	O	-	O	-
	LTE 13	-	-	O	O	-	-	O	O	-	-	O	-	O	-
Band Edge Compliance	LTE 4	O	O	O	O	O	O	O	O	O	-	O	O	-	O
	LTE 12	O	O	O	O	-	-	O	O	O	-	O	O	-	O
	LTE 13	-	-	O	O	-	-	O	O	O	-	O	O	-	O
Peak-to-Average Power Ratio	LTE 4	O	O	O	O	O	O	O	O	-	-	O	-	O	-
	LTE 12	O	O	O	O	-	-	O	O	-	-	O	-	O	-
	LTE 13	-	-	O	O	-	-	O	O	-	-	O	-	O	-
Frequency Stability	LTE 4	O	O	O	O	O	O	O	O	-	-	O	-	O	-
	LTE 12	O	O	O	O	-	-	O	O	-	-	O	-	O	-
	LTE 13	-	-	O	O	-	-	O	O	-	-	O	-	O	-
Spurious Emissions at Antenna Terminals	LTE 4	O	O	O	O	O	O	O	-	O	-	-	O	O	O
	LTE 12	O	O	O	O	-	-	O	-	O	-	-	O	O	O
	LTE 13	-	-	O	O	-	-	O	-	O	-	-	O	O	O

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Radiates Spurious Emission	LTE 4	-	-	-	-	-	O	O	-	O	-	-	O	O	O
	LTE 12	-	-	-	O	-	-	O	-	O	-	-	O	O	O
	LTE 13	-	-	-	O	-	-	O	-	O	-	-	O	O	O
Note	1. The mark “O” means that this configuration is chosen for testing. 2. The mark “-” means that this configuration is not testing.														

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5 Test Information

5.1 RF Power Output

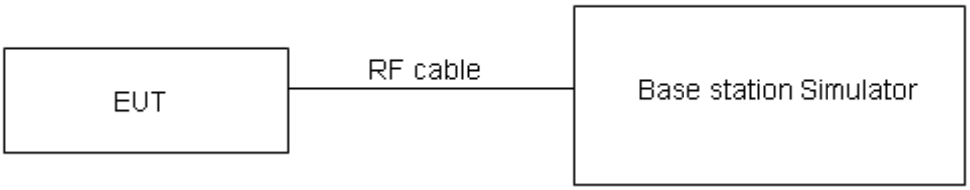
Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Methods of Measurement

During the process of the testing, The EUT is controlled by the Base Station Simulator to ensure max power transmission and proper modulation.

Test Setup



The loss between RF output port of the EUT and the input port of the tester has been taken into consideration.

Limits

No specific RF power output requirements in part 2.1046.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U=0.4 dB.

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Test Results

Mode	Bandwidth	Channel/ Frequency(MHz)	RB	Index	Conducted Power (dBm)	
					QPSK	16QAM
Band4	1.4MHz	19957 1710.7	1#0	0	22.38	21.94
			6#0	0	22.13	22.06
		20175/1732.5	1#0	0	22.31	22.02
			6#0	0	22.09	22.03
		20393/1754.3	1#5	0	22.37	22.13
			6#0	0	22.23	22.21
	3MHz	19965/1711.5	1#0	0	22.40	21.97
			6#0	0	22.16	22.09
		20175/1732.5	1#0	0	22.35	22.04
			6#0	0	22.13	22.07
		20385/1753.5	1#5	1	22.40	22.16
			6#0	1	22.26	22.24
	5MHz	19975/1712.5	1#0	0	22.37	21.94
			6#0	0	22.14	22.07
		20175/1732.5	1#0	0	22.33	22.00
			6#0	0	22.12	22.03
		20375/1752.5	1#5	3	22.36	22.13
			6#0	3	22.24	22.19
	10MHz	20000/1715	1#0	0	22.39	21.96
			4#0	0	22.22	22.10
		20175/1732.5	1#0	0	22.34	22.03
			4#0	0	22.14	22.08
		20350/1750	1#5	7	22.39	22.15
			4#2	7	22.28	22.23
	15MHz	20025/1717.5	1#0	0	22.38	21.91
			6#0	0	22.20	22.07
		20175/1732.5	1#0	0	22.30	22.01
			6#0	0	22.10	22.03
		20325/1747.5	1#5	11	22.37	22.13
			6#0	11	22.23	22.19
	20MHz	20050/1720	1#0	0	22.35	21.89
			6#0	0	22.17	22.05
		20175/1732.5	1#0	0	22.26	21.97
			6#0	0	22.05	21.99
		20300/1745	1#5	15	22.34	22.08
			6#0	15	22.19	22.16

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Mode	Bandwidth	Channel/ Frequency(MHz)	RB	Index	Conducted Power (dBm)	
					QPSK	16QAM
Band12	1.4MHz	23017/699.7	1#0	0	22.74	23.23
			6#0	0	22.48	22.71
		23095/707.5	1#0	0	23.12	22.81
			6#0	0	22.66	22.90
		23173/715.3	1#5	0	23.37	23.02
			6#0	0	22.64	22.79
	3MHz	23025/700.5	1#0	0	22.76	23.25
			6#0	0	22.56	22.74
		23095/707.5	1#0	0	23.13	22.84
			6#0	0	22.68	22.95
		23165/714.5	1#5	1	23.40	23.04
			6#0	1	22.68	22.83
	5MHz	23035/701.5	1#0	0	22.75	23.20
			6#0	0	22.54	22.71
		23095/707.5	1#0	0	23.09	22.82
			6#0	0	22.64	22.90
		23155/713.5	1#5	3	23.38	23.02
			6#0	3	22.63	22.79
	10MHz	23060/704	1#0	0	22.72	23.18
			4#0	0	22.51	22.69
		23095/707.5	1#0	0	23.05	22.78
			4#0	0	22.59	22.86
		23130/711	1#5	7	23.35	22.97
			4#2	7	22.59	22.76

Mode	Bandwidth	Channel/ Frequency(MHz)	RB	Index	Conducted Power (dBm)	
					QPSK	16QAM
Band13	5MHz	23205/779.5	1#0	0	23.10	23.81
			6#0	0	22.80	21.84
		23230/782	1#0	0	23.32	23.14
			6#0	0	22.68	22.19
		23255/784.5	1#5	3	23.11	23.72
			6#0	3	22.67	21.93
	10MHz	23230/782	1#0	0	23.07	23.70
			4#0	0	22.77	22.95

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5.2 Effective Isotropic Radiated Power

Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Methods of Measurement

1. The testing follows FCC KDB 971168 D01 v03r01 Section 5.8 and ANSI C63.26 (2015).

a) Connect the equipment as illustrated. Mount the equipment with the manufacturer specified antenna in a vertical orientation on a manufacturer specified mounting surface located on a non-conducting rotating platform of a RF anechoic chamber (preferred) or a standard radiation site.

b) Key the transmitter, then rotate the EUT 360° azimuthally and record spectrum analyzer power level (LVL) measurements at angular increments that are sufficiently small to permit resolution of all peaks. If a standard radiation test site is used, raise and lower the test antenna to obtain a maximum reading at each angular increment. (Note: several batteries may be needed to offset the effect of battery voltage droop, which should not exceed 5% of the manufactured specified battery voltage during transmission).

c) Replace the transmitter under test with a vertically polarized half-wave dipole (or an antenna whose gain is known relative to an ideal half-wave dipole). The center of the antenna should be at the same location as the center of the antenna under test.

d) Connect the antenna to a signal generator with a known output power and record the path loss (in dB) as LOSS. If a standard radiation test site is used, raise and lower the test antenna to obtain a maximum reading.LOSS = Generator Output Power (dBm) – Analyzer reading (dBm)

e) Determine the effective radiated output power at each angular position from the readings in steps b) and d) using the following equation:ERP (dBm) = LVL (dBm) + LOSS (dB)

f) The maximum ERP is the maximum value determined in the preceding step.

g) When calculating ERP, in addition to knowing the antenna radiation and matching characteristics, it is necessary to know the loss values of all elements (e.g.transmission line attenuation, mismatches, filters, combiners) interposed between the point where transmitter output power is measured, and the point where power is applied to the antenna. ERP can then be calculated as follows:

EIRP (dBm) = Output Power (dBm) - Losses (dB) + Antenna Gain (dBi)

where:dBd refers to gain relative to an ideal dipole.

EIRP (dBm) = ERP (dBm) + 2.15 (dB.)

The RB allocation refers to section 5.1, using the maximum output power configuration.

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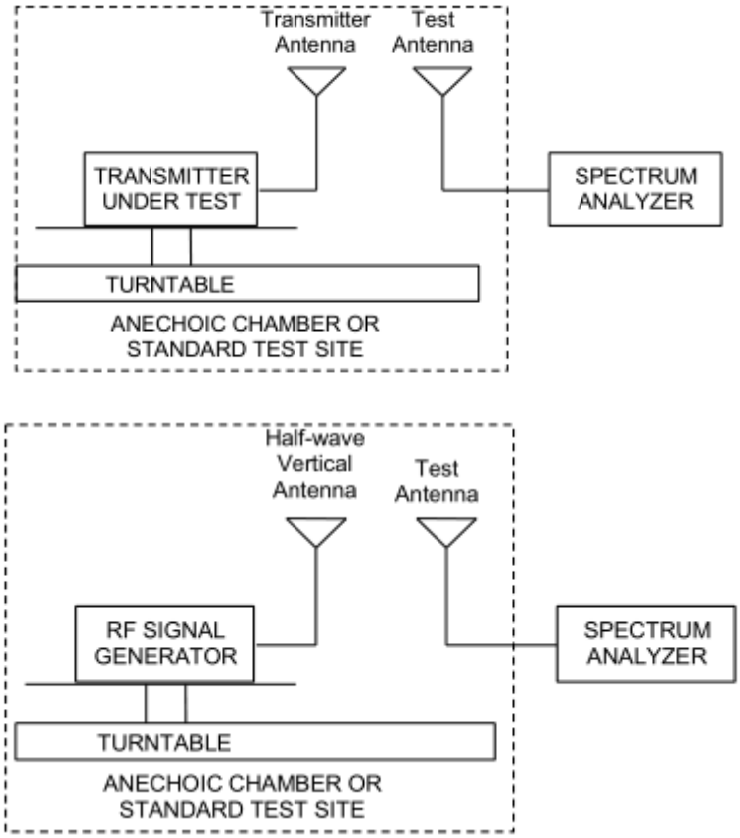
Test setup



Note: Area side:2.4mX3.6m

The radiated emission was measured in the following position: EUT stand-up position (Z axis), lie-down position (X, Y axis). The worst emission was found in stand-up position (Z axis) and the worst case was recorded.

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Limits

Rule Part 27.50(b) (10) specifies that “Portable stations (hand-held devices) transmitting in the 746-757 MHz, 776-788 MHz, and 805-806 MHz bands are limited to 3 watts ERP”

Rule Part 27.50(c) (10) specifies that “Portable stations (hand-held devices) in the 600 MHz uplink band and the 698-746 MHz band, and fixed and mobile stations in the 600 MHz uplink band are limited to 3 watts ERP”

Rule Part 27.50(d) (4) specifies that “Fixed, mobile and portable (hand-held) stations operating in the 1710–1755 MHz band are limited to 1 watt EIRP”

Part 27.50(b)(10)Limit	≤ 3 W (34.77 dBm)
Part 27.50(c)(10)Limit	≤ 3 W (34.77 dBm)
Part 27.50(d)(4)Limit	≤ 1 W (30 dBm)

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U= 1.19 dB

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Test Results

The measurement is performed for both of horizontal and vertical antenna Polarization, and only the data of worst mode is recorded in this report.

LTE Band 4							
Band width	Channel/ Frequency (MHz)	Polarization	RB	Index	EIRP (dBm)	Limit (dBm)	Conclusion
1.4MHz (QPSK)	19957/1710.7	Horizontal	1#0	0	29.04	30	pass
	20175/1732.5	Horizontal	1#2	0	29.25	30	pass
	20393/1754.3	Horizontal	1#5	0	29.52	30	pass
3MHz (QPSK)	19965/1711.5	Horizontal	1#0	0	29.25	30	pass
	20175/1732.5	Horizontal	1#5	0	29.98	30	pass
	20385/1753.5	Horizontal	1#5	1	29.32	30	pass
5MHz (QPSK)	19975/1712.5	Horizontal	1#0	0	29.73	30	pass
	20175/1732.5	Horizontal	1#5	1	29.18	30	pass
	20375/1752.5	Horizontal	1#5	3	29.29	30	pass
10MHz (QPSK)	20000/1715	Horizontal	4#0	0	29.05	30	pass
	20175/1732.5	Horizontal	4#2	3	29.24	30	pass
	20350/1750	Horizontal	4#2	7	29.47	30	pass
15MHz (QPSK)	20025/1717.5	Horizontal	1#0	0	27.28	30	pass
	20175/1732.5	Horizontal	1#5	5	27.80	30	pass
	20325/1747.5	Horizontal	1#5	11	27.93	30	pass
20MHz (QPSK)	20050/1720	Horizontal	6#0	0	26.65	30	pass
	20175/1732.5	Horizontal	6#0	7	26.95	30	pass
	20300/1745	Horizontal	6#0	15	26.06	30	pass
1.4MHz (16QAM)	19957/1710.7	Horizontal	1#0	0	29.72	30	pass
	20175/1732.5	Horizontal	1#2	0	29.94	30	pass
	20393/1754.3	Horizontal	1#5	0	29.21	30	pass
3MHz (16QAM)	19965/1711.5	Horizontal	1#0	0	29.95	30	pass
	20175/1732.5	Horizontal	1#5	0	29.66	30	pass
	20385/1753.5	Horizontal	1#5	1	29.01	30	pass
5MHz (16QAM)	19975/1712.5	Horizontal	1#0	0	29.41	30	pass
	20175/1732.5	Horizontal	1#5	1	29.55	30	pass
	20375/1752.5	Horizontal	1#5	3	29.00	30	pass
10MHz (16QAM)	20000/1715	Horizontal	4#0	0	28.70	30	pass
	20175/1732.5	Horizontal	4#2	3	28.92	30	pass
	20350/1750	Horizontal	4#2	7	29.15	30	pass
15MHz (16QAM)	20025/1717.5	Horizontal	1#0	0	26.97	30	pass
	20175/1732.5	Horizontal	1#5	5	27.50	30	pass
	20325/1747.5	Horizontal	1#5	11	27.62	30	pass
20MHz	20050/1720	Horizontal	6#0	0	26.32	30	pass

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(16QAM)	20175/1732.5	Horizontal	6#0	7	26.63	30	pass
	20300/1745	Horizontal	6#0	15	25.75	30	pass

LTE Band 12							
Band width	**Frequency (MHz)**	**Polarization**	**RB**	**Index**	**EIRP (dBm)**	**Limit (dBm)**	**Conclusion**
1.4MHz (QPSK)	23017/699.7	Horizontal	1#0	0	25.51	34.7	pass
	23095/707.5	Horizontal	1#2	0	26.10	34.7	pass
	23173/715.3	Horizontal	1#5	0	26.92	34.7	pass
3MHz (QPSK)	23025/700.5	Horizontal	1#0	0	25.50	34.7	pass
	23095/707.5	Horizontal	1#5	0	26.79	34.7	pass
	23165/714.5	Horizontal	1#5	1	27.79	34.7	pass
5MHz (QPSK)	23035/701.5	Horizontal	1#0	0	25.36	34.7	pass
	23095/707.5	Horizontal	1#5	1	26.32	34.7	pass
	23155/713.5	Horizontal	1#5	3	27.30	34.7	pass
10MHz (QPSK)	23060/704	Horizontal	4#0	0	24.70	34.7	pass
	23095/707.5	Horizontal	4#2	3	25.44	34.7	pass
	23130/711	Horizontal	4#2	7	25.97	34.7	pass
1.4MHz (16QAM)	23017/699.7	Horizontal	1#0	0	25.18	34.7	pass
	23095/707.5	Horizontal	1#2	0	25.80	34.7	pass
	23173/715.3	Horizontal	1#5	0	27.60	34.7	pass
3MHz (16QAM)	23025/700.5	Horizontal	1#0	0	25.17	34.7	pass
	23095/707.5	Horizontal	1#5	0	26.45	34.7	pass
	23165/714.5	Horizontal	1#5	1	27.47	34.7	pass
5MHz (16QAM)	23035/701.5	Horizontal	1#0	0	25.07	34.7	pass
	23095/707.5	Horizontal	1#5	1	26.00	34.7	pass
	23155/713.5	Horizontal	1#5	3	26.98	34.7	pass
10MHz (16QAM)	23060/704	Horizontal	4#0	0	24.40	34.7	pass
	23095/707.5	Horizontal	4#2	3	25.10	34.7	pass
	23130/711	Horizontal	4#2	7	25.66	34.7	pass

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LTE Band 13							
Band width	**Frequency (MHz)**	**Polarization**	**RB**	**Index**	**EIRP (dBm)**	**Limit (dBm)**	**Conclusion**
5MHz (QPSK)	23205/779.5	Horizontal	1#0	0	27.00	34.7	pass
	23230/782	Horizontal	1#5	1	26.97	34.7	pass
	23255/784.5	Horizontal	1#5	3	27.00	34.7	pass
10MHz (QPSK)	23230/782	Horizontal	4#2	3	26.86	34.7	pass
5MHz (16QAM)	23035/701.5	Horizontal	1#0	0	26.99	34.7	pass
	23095/707.5	Horizontal	1#5	1	26.96	34.7	pass
	23155/713.5	Horizontal	1#5	3	27.17	34.7	pass
10MHz (16QAM)	23230/782	Horizontal	4#2	3	26.55	34.7	pass

Note: 1. EIRP= E.R.P+2.15

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5.3 Occupied Bandwidth

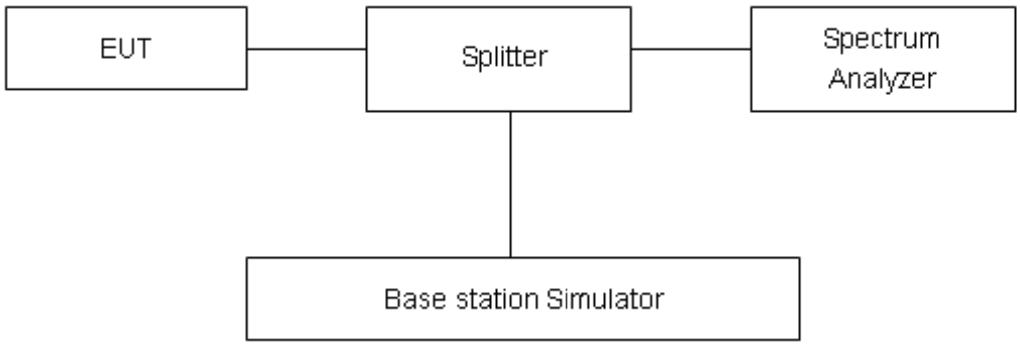
Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Method of Measurement

The EUT was connected to Spectrum Analyzer and Base Station Simulator via power Splitter. The occupied bandwidth is measured using spectrum analyzer.
RBW is set to 51 kHz, VBW is set to 160 kHz for LTE Band 4/12/13 .
99% power and -26dBc occupied bandwidths are recorded. Spectrum analyzer plots are included on the following pages.

Test Setup



Limits

No specific occupied bandwidth requirements in part 2.1049.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U=624Hz.

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Test Result

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	RB	Index	Bandwidth(MHz)	
						99% Power	-26dBc
Band4	1.4MHz	QPSK	20175/1732.5	6#0	0	1.1180	1.345
		16QAM	20175/1732.5	6#0	0	0.93883	1.215
	3MHz	QPSK	20175/1732.5	6#0	0	1.15040	1.655
		16QAM	20175/1732.5	6#0	0	0.98073	1.337
	5MHz	QPSK	20175/1732.5	6#0	0	1.13010	1.472
		16QAM	20175/1732.5	6#0	0	1.0162	1.496
	10MHz	QPSK	20175/1732.5	6#0	0	1.1840	1.796
		16QAM	20175/1732.5	6#0	0	1.0660	1.795
	15MHz	QPSK	20175/1732.5	6#0	0	1.1955	1.894
		16QAM	20175/1732.5	6#0	0	1.0578	1.889
	20MHz	QPSK	20175/1732.5	6#0	0	1.2079	1.782
		16QAM	20175/1732.5	6#0	0	1.1125	1.862

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	RB	Index	Bandwidth(MHz)	
						99% Power	-26dBc
Band12	1.4MHz	QPSK	23095/707.5	6#0	0	1.1082	1.332
		16QAM	23095/707.5	6#0	0	0.93878	1.195
	3MHz	QPSK	23095/707.5	6#0	0	1.1525	1.66
		16QAM	23095/707.5	6#0	0	0.98517	1.343
	5MHz	QPSK	23095/707.5	6#0	0	1.1445	1.506
		16QAM	23095/707.5	6#0	0	0.97604	1.423
	10MHz	QPSK	23095/707.5	6#0	0	1.2051	1.738
		16QAM	23095/707.5	6#0	0	1.0835	1.731

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	RB	Index	Bandwidth(MHz)	
						99% Power	-26dBc
Band13	5MHz	QPSK	23230/782	6#0	0	1.149	1.481
		16QAM	23230/782	6#0	0	0.97695	1.356
	10MHz	QPSK	23230/782	6#0	0	1.1775	1.721
		16QAM	23230/782	6#0	0	1.0331	1.537

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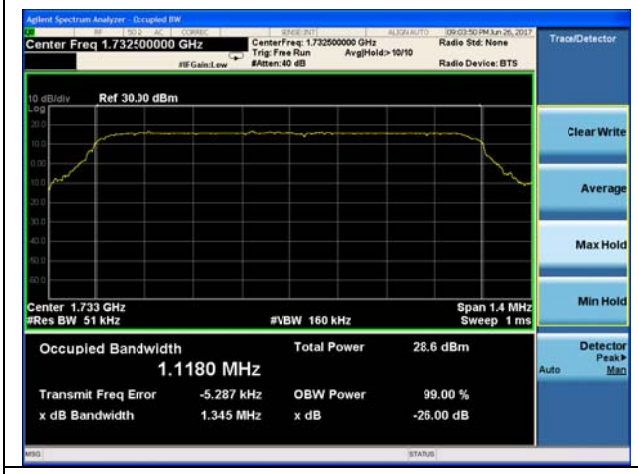
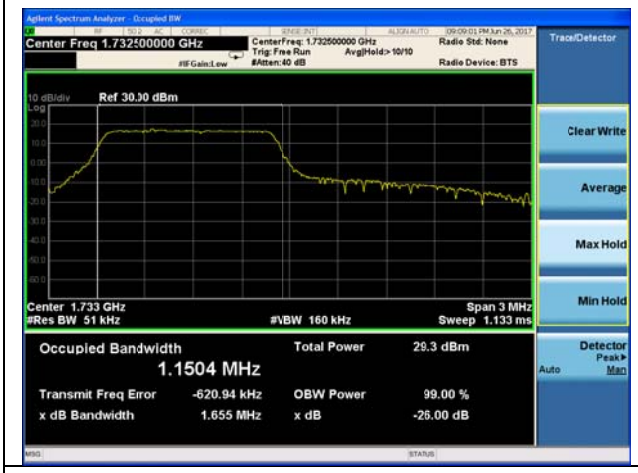
LTE Band 4 QPSK 1.4MHz CH-Middle



LTE Band 4 16QAM 1.4MHz CH-Middle

LTE Band 4 QPSK 3MHz CH-Middle



LTE Band 4 16QAM 3MHz CH-Middle

LTE Band 4 QPSK 5MHz CH-Middle

LTE Band 4 16QAM 5MHz CH-Middle

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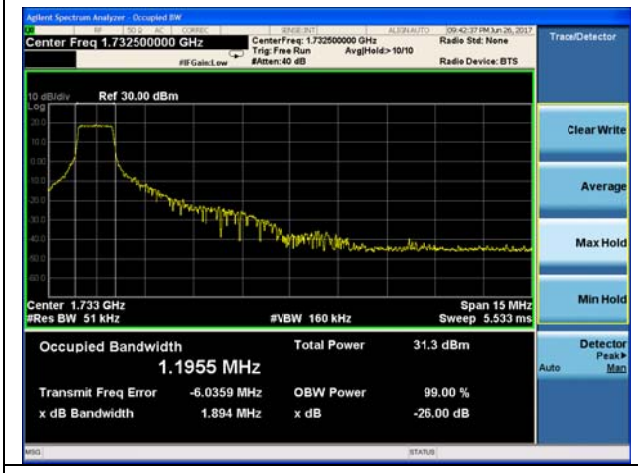
LTE Band 4 QPSK 10MHz CH-Middle

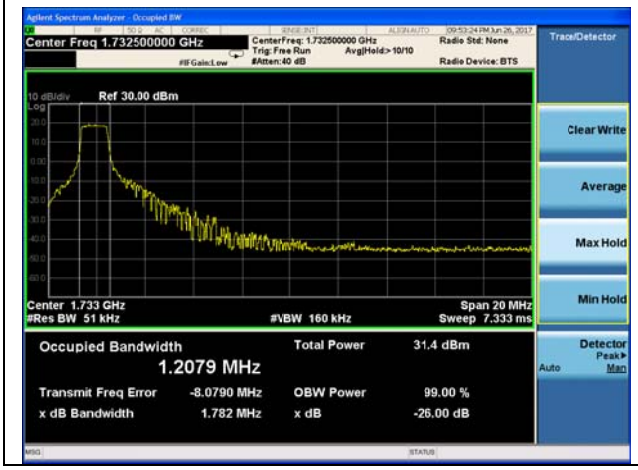
LTE Band 4 16QAM 10MHz CH-Middle

LTE Band 4 QPSK 15MHz CH-Middle



LTE Band 4 16QAM 15MHz CH-Middle

LTE Band 4 QPSK 20MHz CH-Middle



LTE Band 4 16QAM 20MHz CH-Middle

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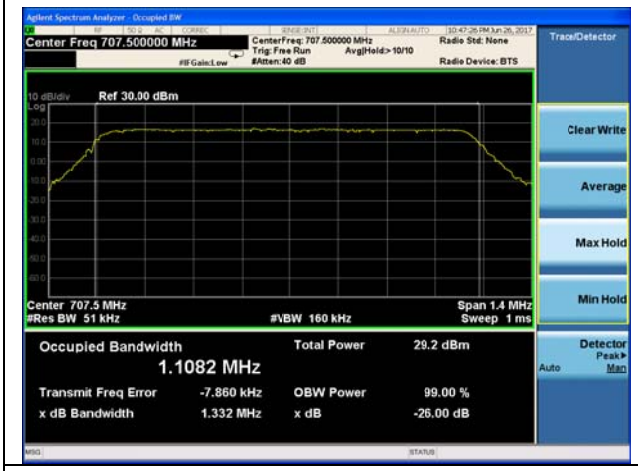
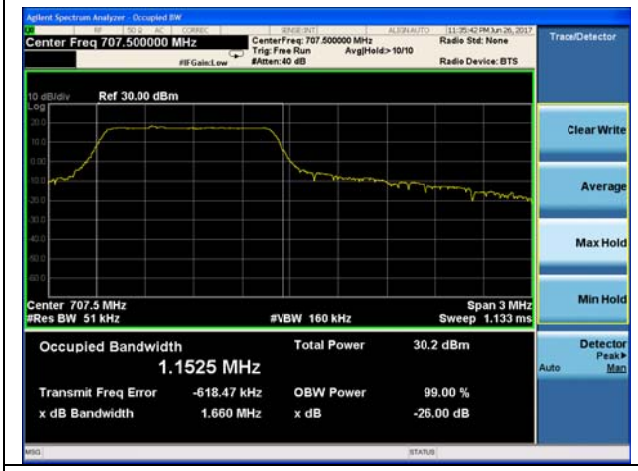
LTE Band 12 QPSK 1.4MHz CH-Middle



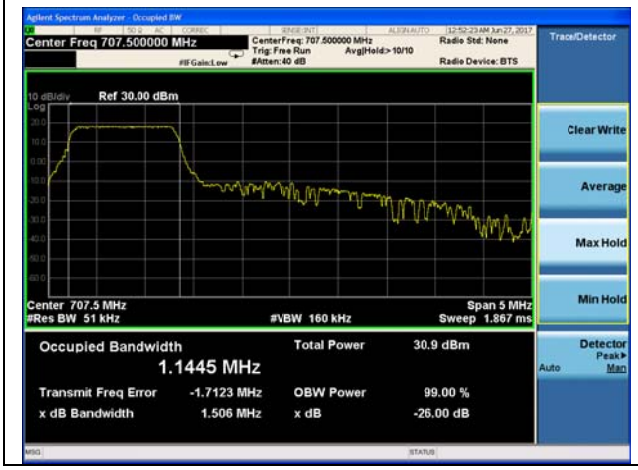
LTE Band 12 16QAM 1.4MHz CH-Middle

LTE Band 12 QPSK 3MHz CH-Middle



LTE Band 12 16QAM 3MHz CH-Middle

LTE Band 12 QPSK 5MHz CH-Middle



LTE Band 12 16QAM 5MHz CH-Middle

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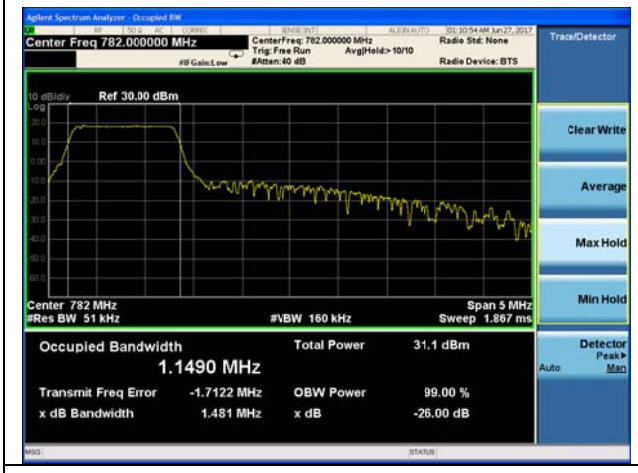
LTE Band 12 QPSK 10MHz CH-Middle

LTE Band 12 16QAM 10MHz CH-Middle

LTE Band 13 QPSK 5MHz CH-Middle



LTE Band 13 16QAM 5MHz CH-Middle

LTE Band 13 QPSK 10MHz CH-Middle

LTE Band 13 16QAM 10MHz CH-Middle

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5.4 Band Edge Compliance

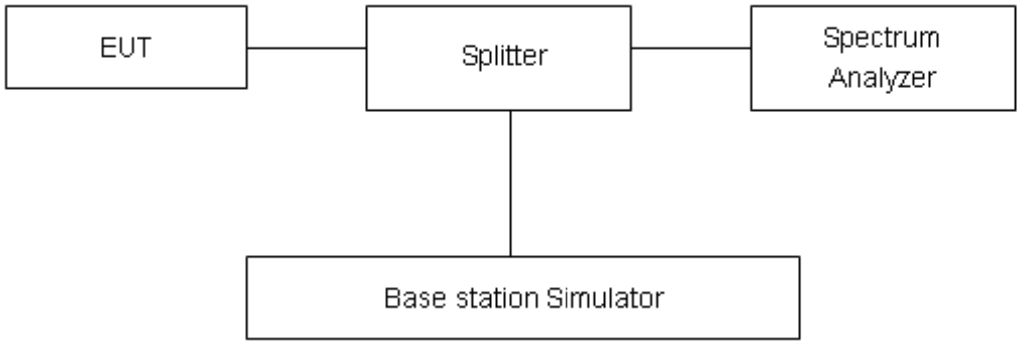
Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Method of Measurement

The EUT was connected to Spectrum Analyzer and Base Station Simulator via power Splitter. The band edge of the lowest and highest channels were measured.
The testing follows KDB 971168 v02r02 Section 6.0
The EUT was connected to spectrum analyzer and system simulator via a power divider.
The band edges of low and high channels for the highest RF powers were measured.
RBW is set to 51 kHz, VBW is set to 160 kHz for LTE Band 4/12/13 on spectrum analyzer.
Set spectrum analyzer with RMS detector.
The RF fundamental frequency should be excluded against the limit line in the operating frequency band.
Checked that all the results comply with the emission limit line.

Test Setup



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Limits

Rule Part 27.53(h)/ specifies that " for operations in the 1695-1710 MHz, 1710-1755 MHz, 1755-1780 MHz, 1915-1920 MHz, 1995-2000 MHz, 2000-2020 MHz, 2110-2155 MHz, 2155-2180 MHz, and 2180-2200 bands, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 $\log_{10}$ (P) dB"
Part 27.53(g) specifies that " For operations in the 600 MHz band and the 698-746 MHz band, the power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) within the licensed band(s) of operation, measured in watts, by at least 43 + 10 log10 (P) dB."
Part 27.53(m) (4)/ specifies that "for BRS and EBS stations. For mobile digital stations, the attenuation factor shall be not less than 40 + 10 log (P) dB on all frequencies between the channel edge and 5 megahertz from the channel edge, 43 + 10 log (P) dB on all frequencies between 5 megahertz and X megahertz from the channel edge, and 55 + 10 log (P) dB on all frequencies more than X megahertz from the channel edge, where X is the greater of 6 megahertz or the actual emission bandwidth as defined in paragraph (m)(4) of this section. In addition, the attenuation factor shall not be less that 43 + 10 log (P) dB on all frequencies between 2490.5 MHz and 2496 MHz and 55 + 10 log (P) dB at or below 2490.5 MHz. Mobile Satellite Service licensees operating on frequencies below 2495 MHz may also submit a documented interference complaint against BRS licensees operating on channel BRS Channel 1 on the same terms and conditions as adjacent channel BRS or EBS licensees.
Example:
The limit line is derived from 43 + 10log (P) dB below the transmitter power P(Watts)
= P(W)- [43 + 10log(P)] (dB)
= [30 + 10log (P)] (dBm) - [43 + 10log(P)] (dB) = -13dBm.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 1.96, U=0.684dB.

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Test Result

All the test traces in the plots shows the test results clearly.

LTE Band 4 QPSK 1.4MHz CH-Low, 1 RB

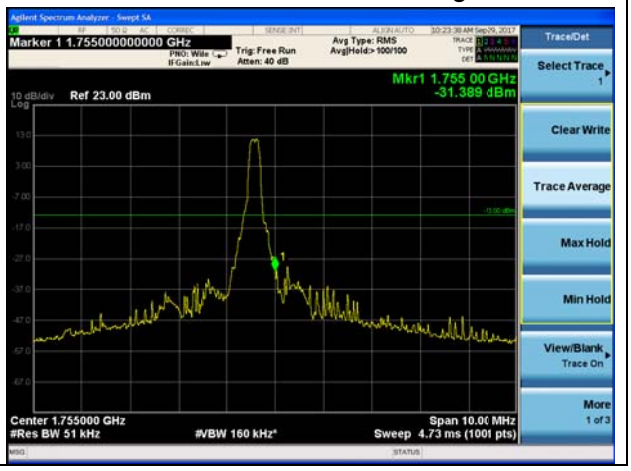
LTE Band 4 QPSK 1.4MHz CH-High, 1 RB

LTE Band 4 QPSK 1.4MHz CH-Low, 100%RB

LTE Band 4 QPSK 1.4MHz CH-High, 100%RB

LTE Band 4 QPSK 3MHz CH-Low, 1 RB

LTE Band 4 QPSK 3MHz CH-High, 1 RB



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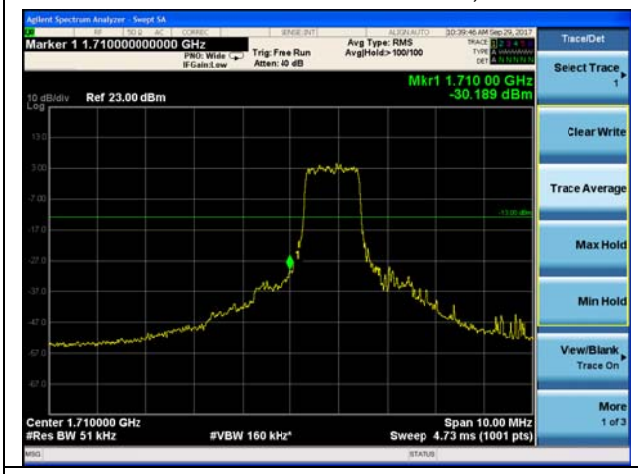
LTE Band 4 QPSK 3MHz CH-Low, 100%RB



LTE Band 4 QPSK 3MHz CH-High, 100%RB

LTE Band 4 QPSK 5MHz CH-Low, 1 RB

LTE Band 4 QPSK 5MHz CH-High, 1 RB

LTE Band 4 QPSK 5MHz CH-Low, 100%RB

LTE Band 4 QPSK 5MHz CH-High, 100%RB

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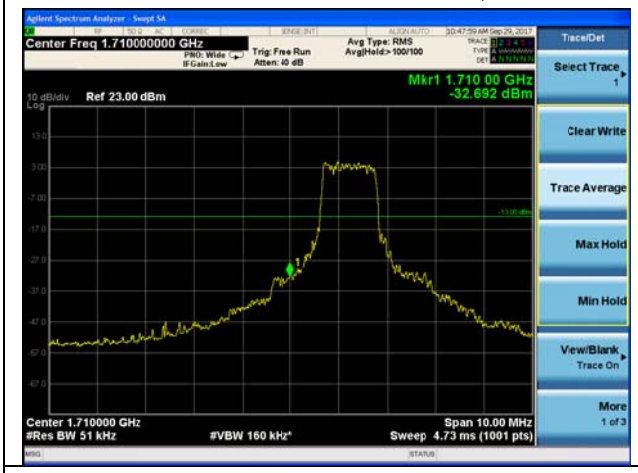
LTE Band 4 QPSK 10MHz CH-Low, 1 RB

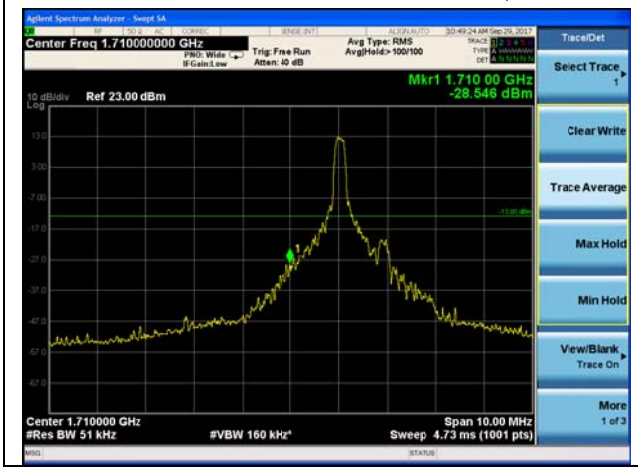
LTE Band 4 QPSK 10MHz CH-High, 1 RB

LTE Band 4 QPSK 10MHz CH-Low, 100%RB



LTE Band 4 QPSK 10MHz CH-High, 100%RB

LTE Band 4 QPSK 15MHz CH-Low, 1 RB



LTE Band 4 QPSK 15MHz CH-High, 1 RB

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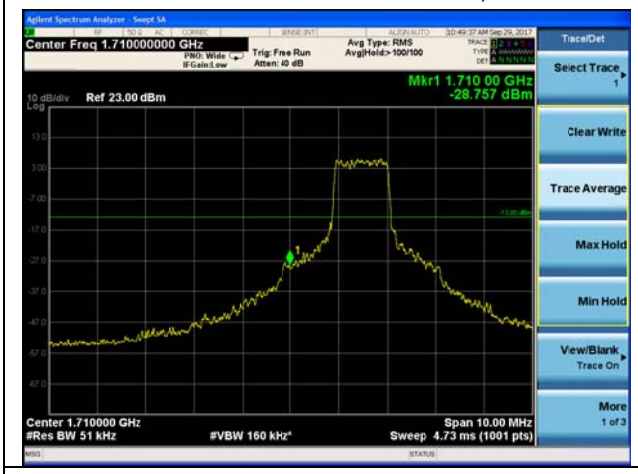
LTE Band 4 QPSK 15MHz CH-Low, 100%RB

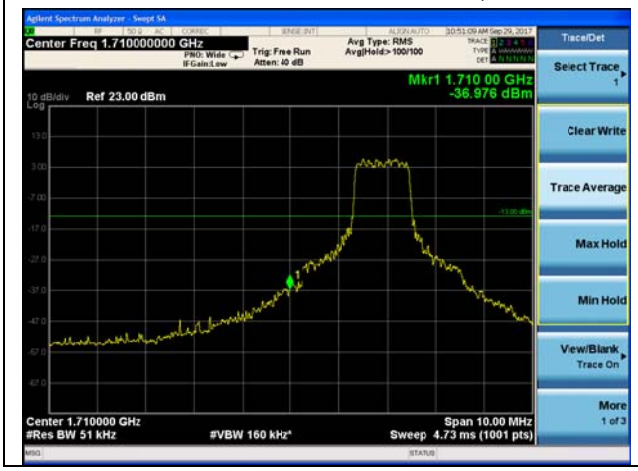


LTE Band 4 QPSK 15MHz CH-High, 100%RB

LTE Band 4 QPSK 20MHz CH-Low, 1 RB

LTE Band 4 QPSK 20MHz CH-High, 1 RB

LTE Band 4 QPSK 20MHz CH-Low, 100%RB



LTE Band 4 QPSK 20MHz CH-High, 100%RB

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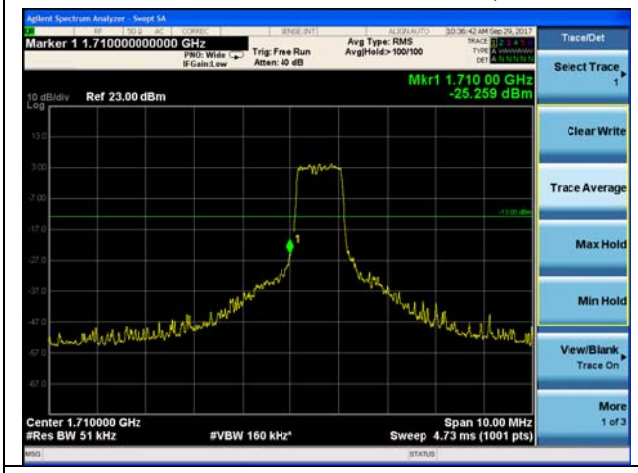
LTE Band 4 16QAM 1.4MHz CH-Low, 1 RB

LTE Band 4 16QAM 1.4MHz CH-High, 1 RB

LTE Band 4 16QAM 1.4MHz CH-Low, 100%RB



LTE Band 4 16QAM 1.4MHz CH-High, 100%RB

LTE Band 4 16QAM 3MHz CH-Low, 1 RB

LTE Band 4 16QAM 3MHz CH-High, 1 RB

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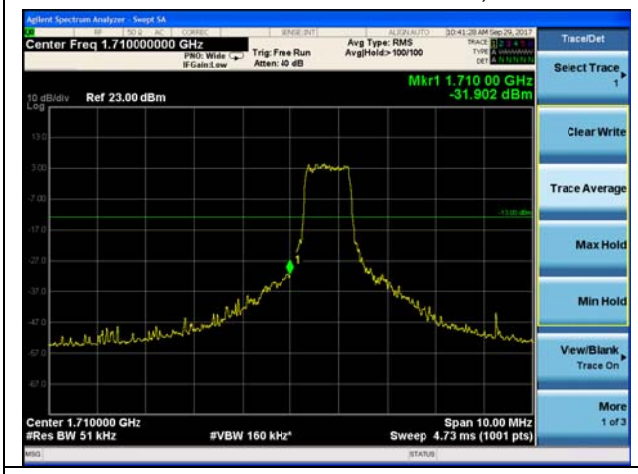
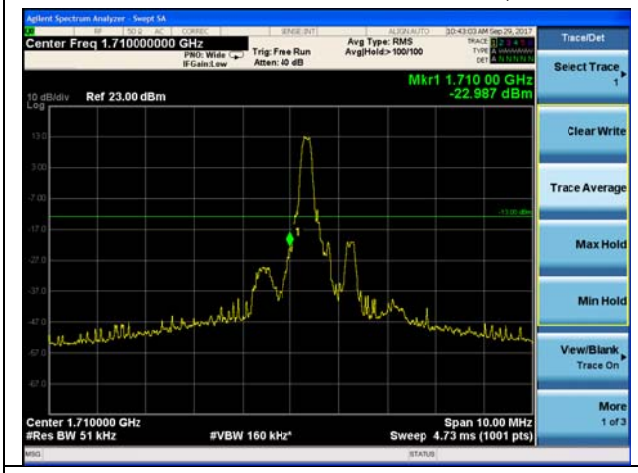
LTE Band 4 16QAM 3MHz CH-Low, 100%RB



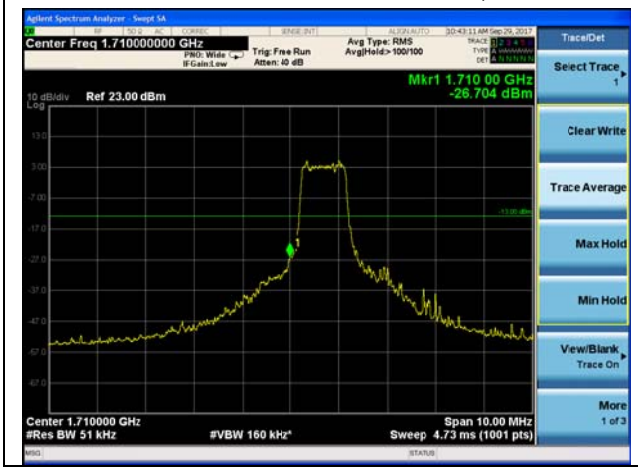
LTE Band 4 16QAM 3MHz CH-High, 100%RB

LTE Band 4 16QAM 5MHz CH-Low, 1 RB



LTE Band 4 16QAM 5MHz CH-High, 1 RB

LTE Band 4 16QAM 5MHz CH-Low, 100%RB



LTE Band 4 16QAM 5MHz CH-High, 100%RB

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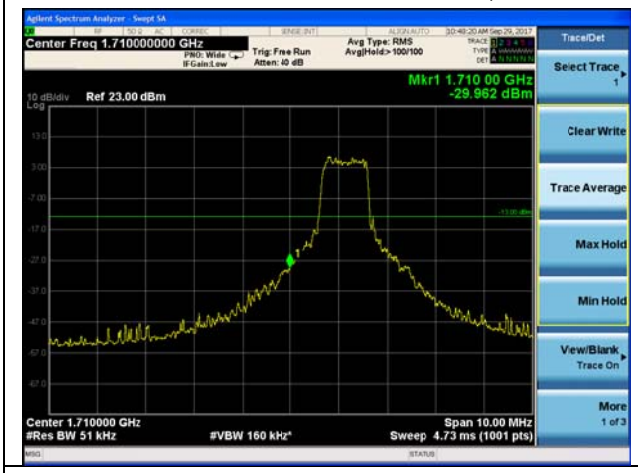
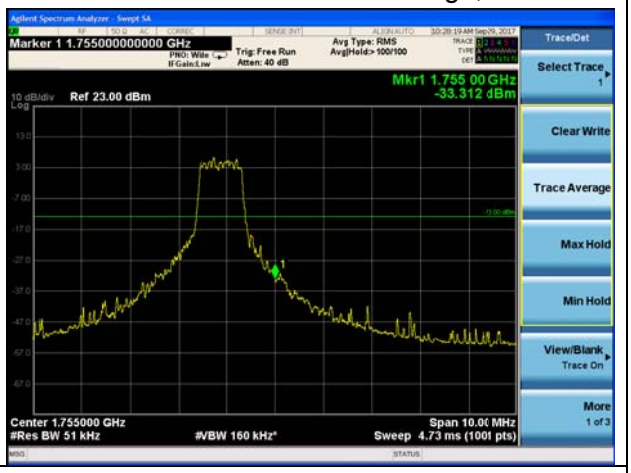
LTE Band 4 16QAM 10MHz CH-Low, 1 RB

LTE Band 4 16QAM 10MHz CH-High, 1 RB

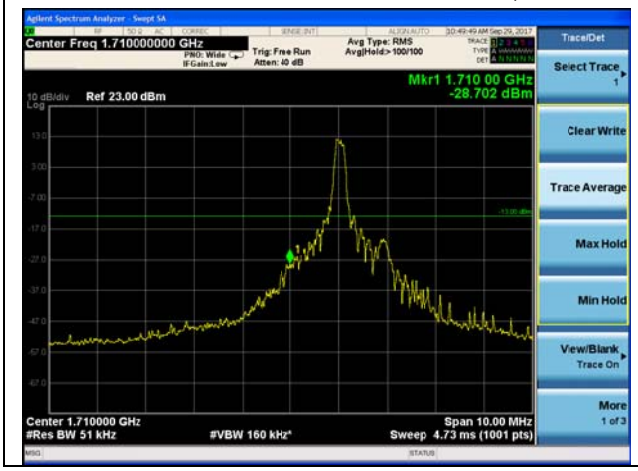
LTE Band 4 16QAM 10MHz CH-Low, 100%RB



LTE Band 4 16QAM 10MHz CH-High, 100%RB



LTE Band 4 16QAM 15MHz CH-Low, 1 RB



LTE Band 4 16QAM 15MHz CH-High, 1 RB

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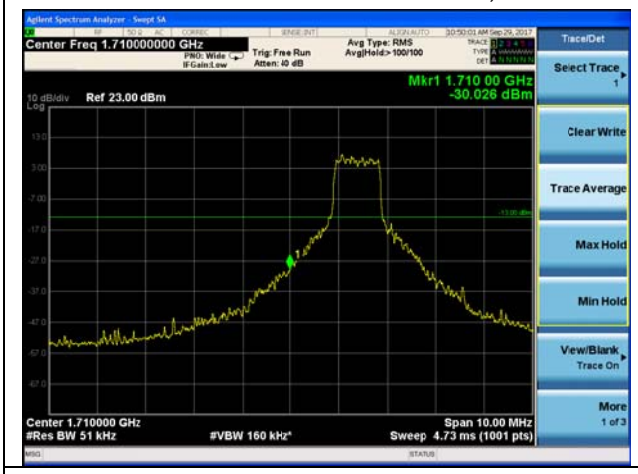
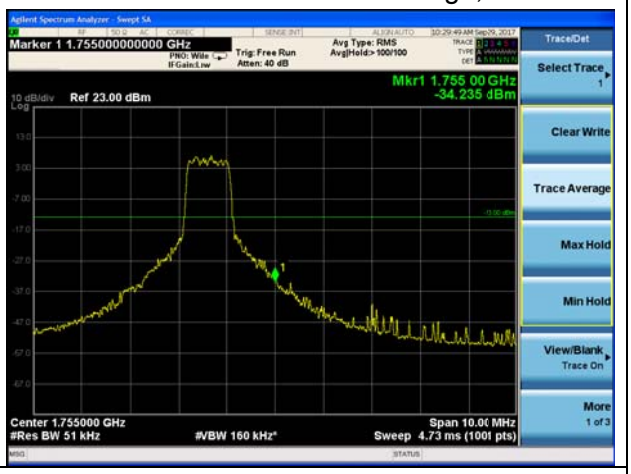
LTE Band 4 16QAM 15MHz CH-Low, 100%RB



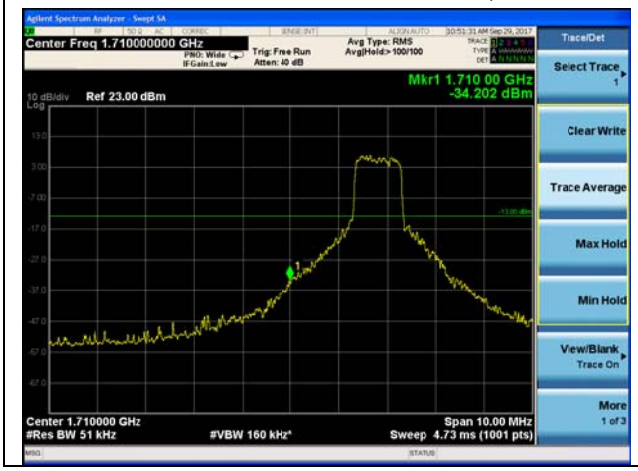
LTE Band 4 16QAM 15MHz CH-High, 100%RB



LTE Band 4 16QAM 20MHz CH-Low, 1 RB

LTE Band 4 16QAM 20MHz CH-High, 1 RB

LTE Band 4 16QAM 20MHz CH-Low, 100%RB



LTE Band 4 16QAM 20MHz CH-High, 100%RB

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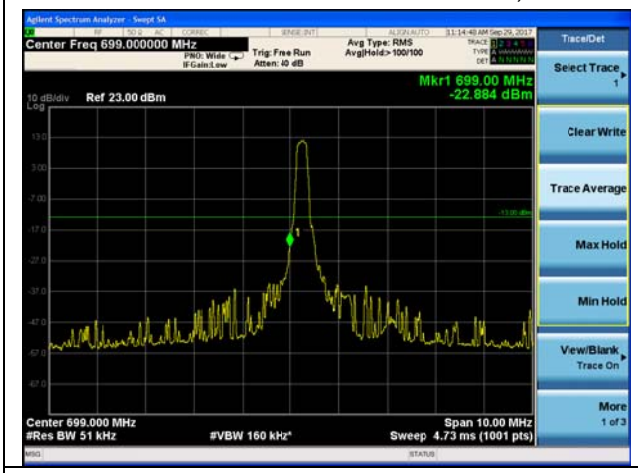
LTE Band 12 QPSK 1.4MHz CH-Low, 1 RB

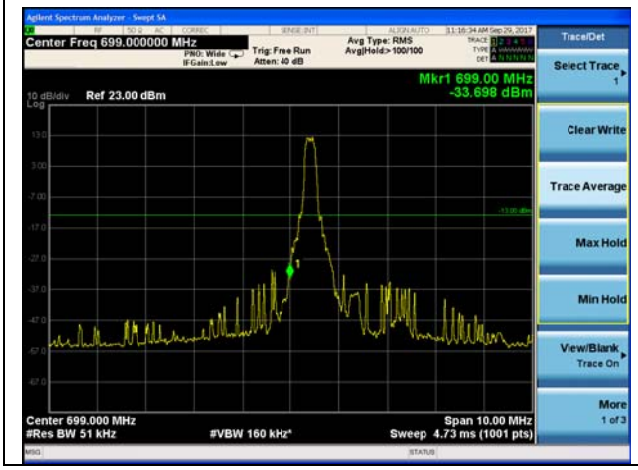


LTE Band 12 QPSK 1.4MHz CH-High, 1 RB

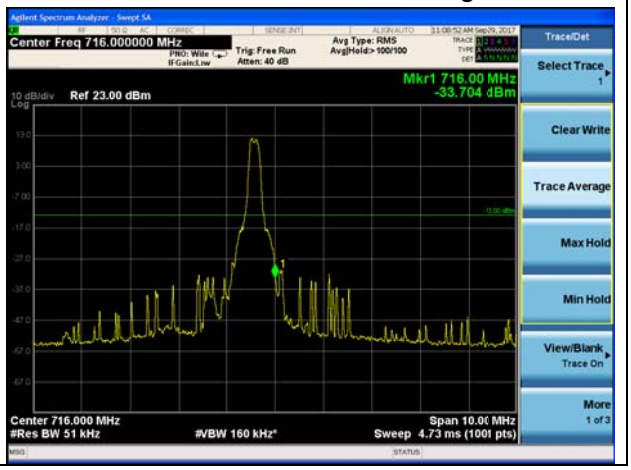
LTE Band 12 QPSK 1.4MHz CH-Low, 100%RB

LTE Band 12 QPSK 1.4MHz CH-High, 100%RB

LTE Band 12 QPSK 3MHz CH-Low, 1 RB



LTE Band 12 QPSK 3MHz CH-High, 1 RB



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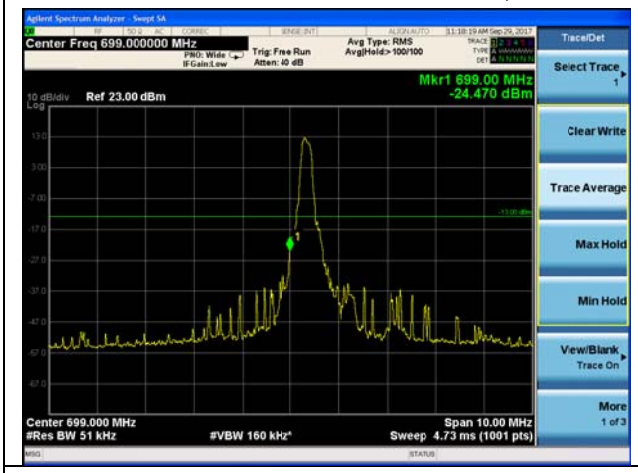
LTE Band 12 QPSK 3MHz CH-Low, 100%RB

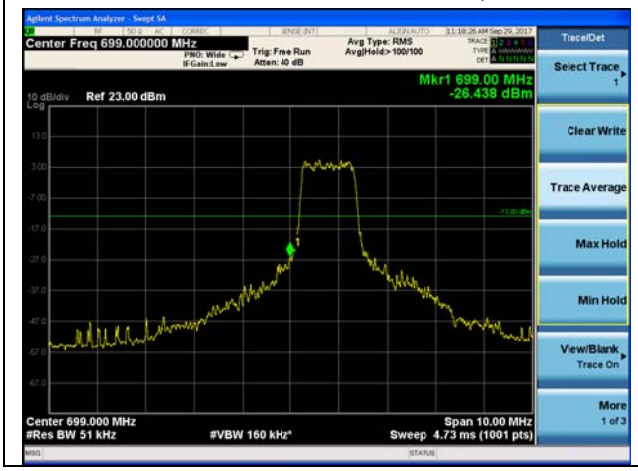
LTE Band 12 QPSK 3MHz CH-High, 100%RB

LTE Band 12 QPSK 5MHz CH-Low, 1 RB



LTE Band 12 QPSK 5MHz CH-High, 1 RB

LTE Band 12 QPSK 5MHz CH-Low, 100%RB



LTE Band 12 QPSK 5MHz CH-High, 100%RB

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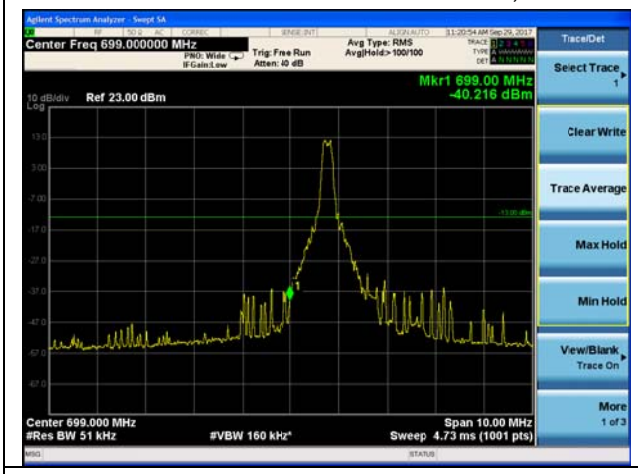
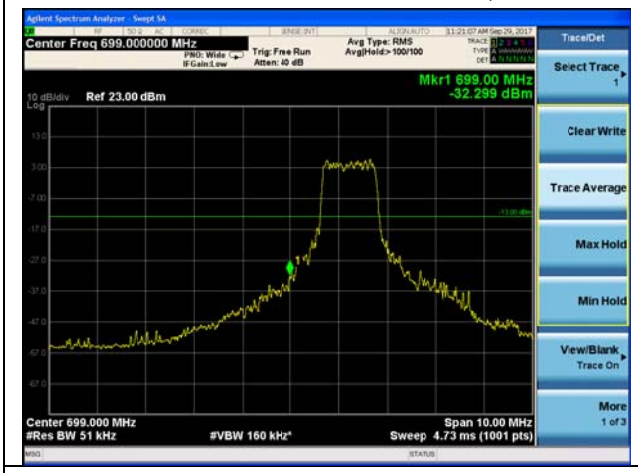
LTE Band 12 QPSK 10MHz CH-Low, 1 RB



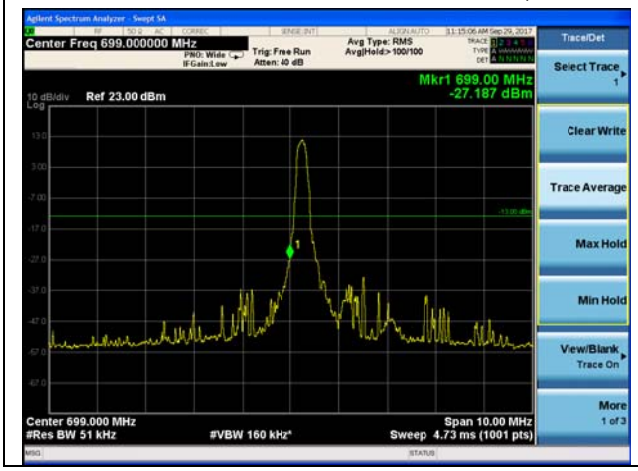
LTE Band 12 QPSK 10MHz CH-High, 1 RB

LTE Band 12 QPSK 10MHz CH-Low, 100%RB



LTE Band 12 QPSK 10MHz CH-High, 100%RB

LTE Band 12 16QAM 1.4MHz CH-Low, 1 RB



LTE Band 12 16QAM 1.4MHz CH-High, 1 RB

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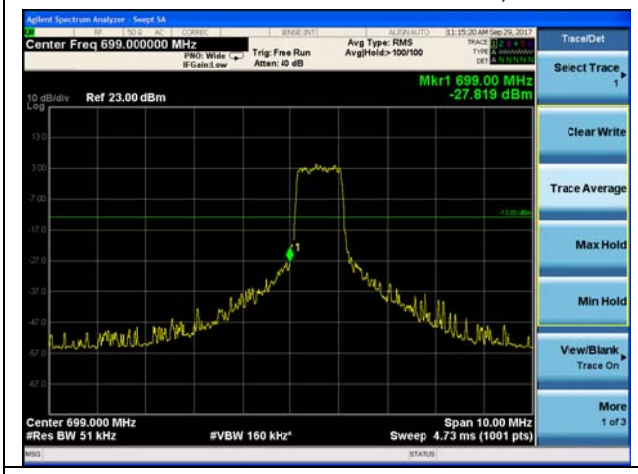
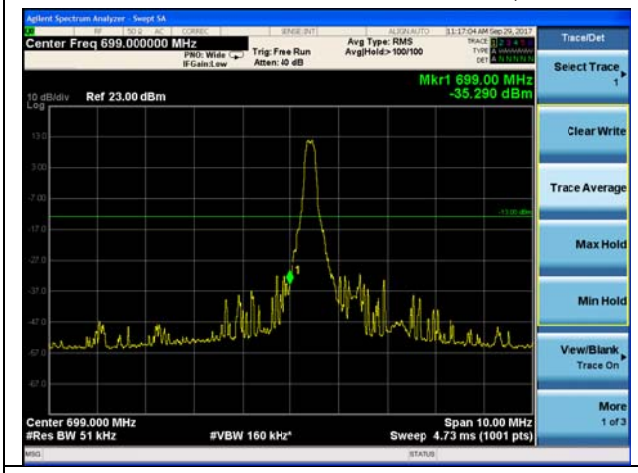
LTE Band 12 16QAM 1.4MHz CH-Low, 100%RB



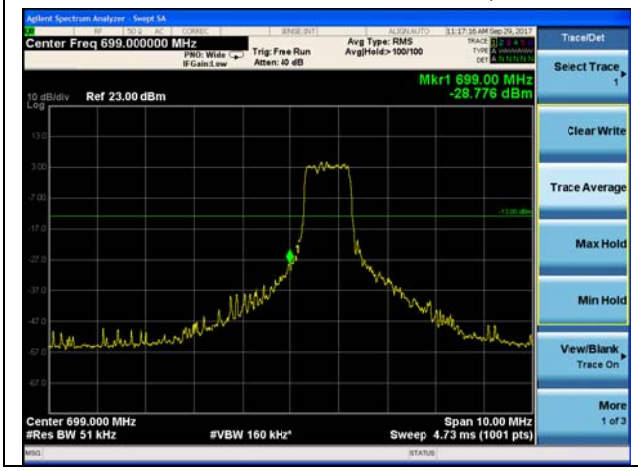
LTE Band 12 16QAM 1.4MHz CH-High, 100%RB

LTE Band 12 16QAM 3MHz CH-Low, 1 RB



LTE Band 12 16QAM 3MHz CH-High, 1 RB

LTE Band 12 16QAM 3MHz CH-Low, 100%RB



LTE Band 12 16QAM 3MHz CH-High, 100%RB

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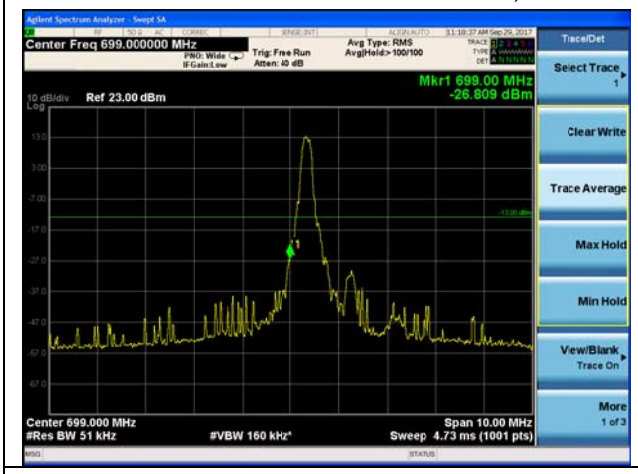
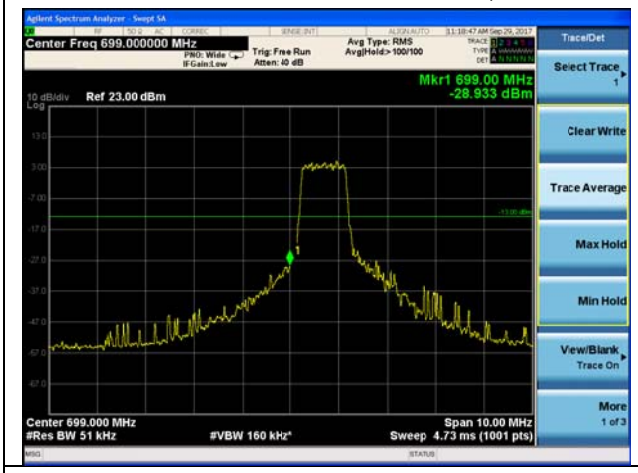
LTE Band 12 16QAM 5MHz CH-Low, 1 RB



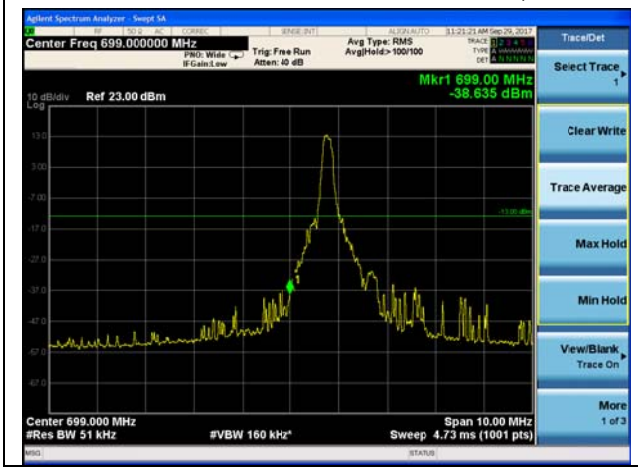
LTE Band 12 16QAM 5MHz CH-High, 1 RB

LTE Band 12 16QAM 5MHz CH-Low, 100%RB

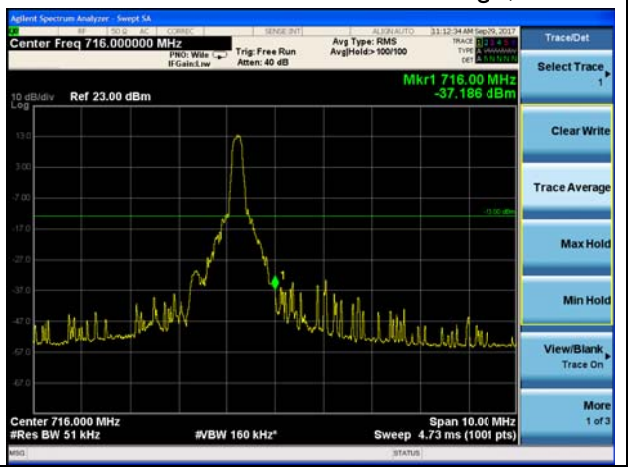


LTE Band 12 16QAM 5MHz CH-High, 100%RB

LTE Band 12 16QAM 10MHz CH-Low, 1 RB



LTE Band 12 16QAM 10MHz CH-High, 1 RB



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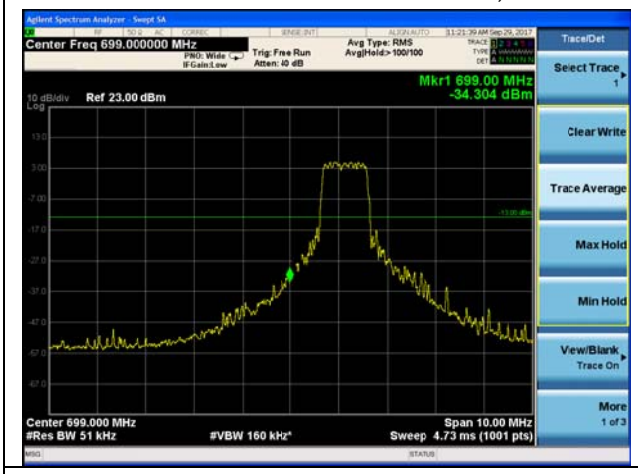
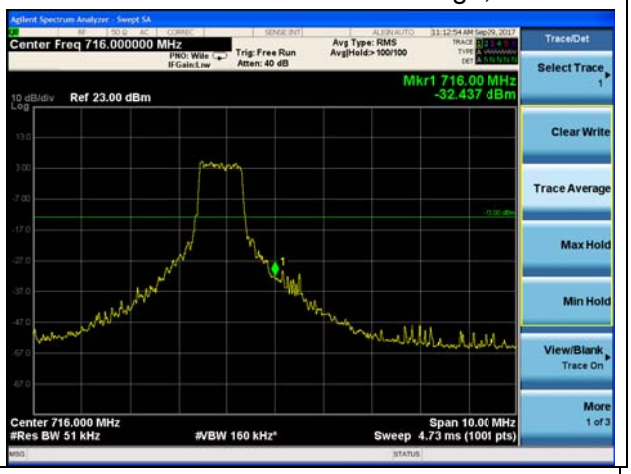
LTE Band 12 16QAM 10MHz CH-Low, 100%RB

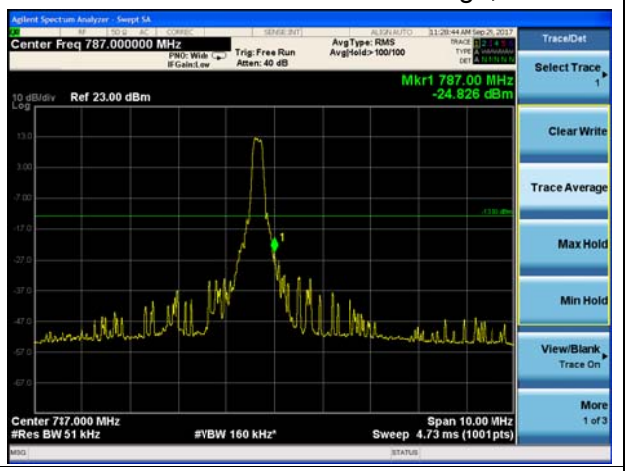


LTE Band 12 16QAM 10MHz CH-High, 100%RB

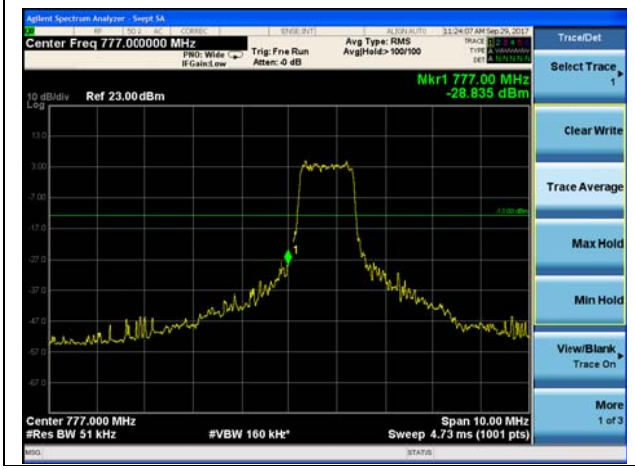


LTE Band 13 QPSK 5MHz CH-Low, 1 RB

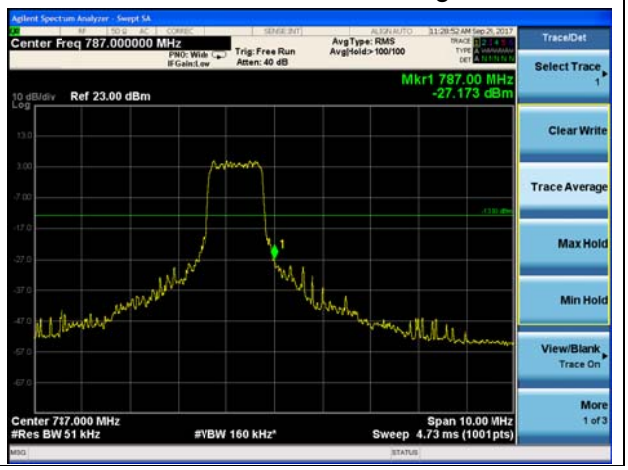
LTE Band 13 QPSK 5MHz CH-High, 1 RB



LTE Band 13 QPSK 5MHz CH-Low, 100%RB



LTE Band 13 QPSK 5MHz CH-High, 100%RB



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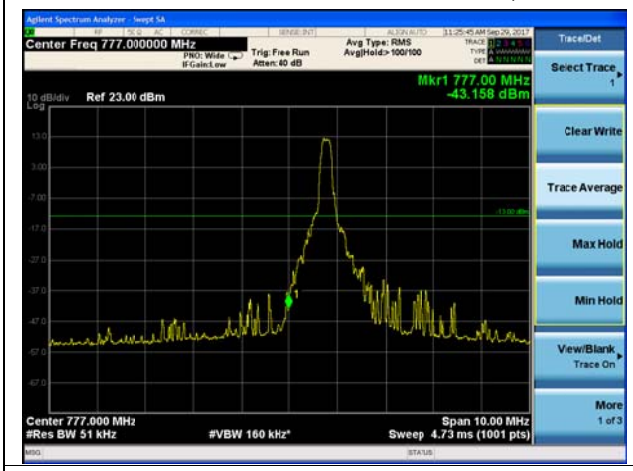
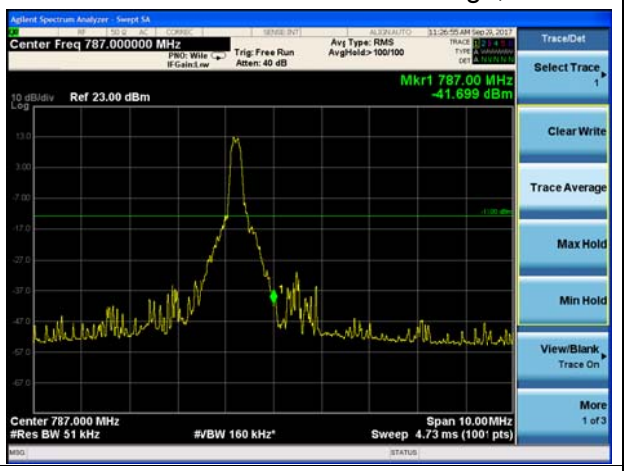
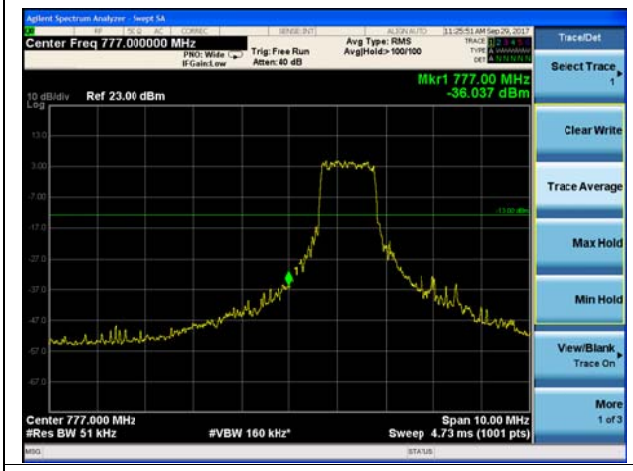
LTE Band 13 QPSK 10MHz CH-Low, 1 RB



LTE Band 13 QPSK 10MHz CH-High, 1 RB

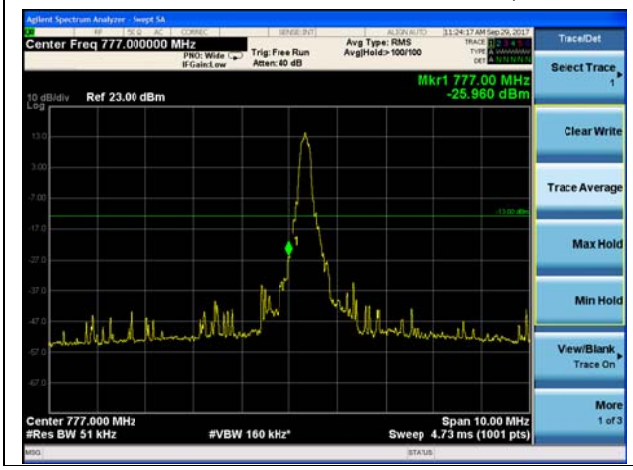


LTE Band 13 QPSK 10MHz CH-Low, 100%RB

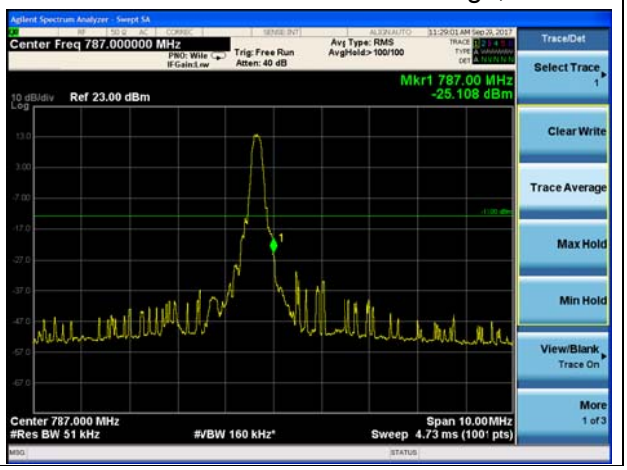


LTE Band 13 QPSK 10MHz CH-High, 100%RB

LTE Band 13 16QAM 5MHz CH-Low, 1 RB



LTE Band 13 16QAM 5MHz CH-High, 1 RB



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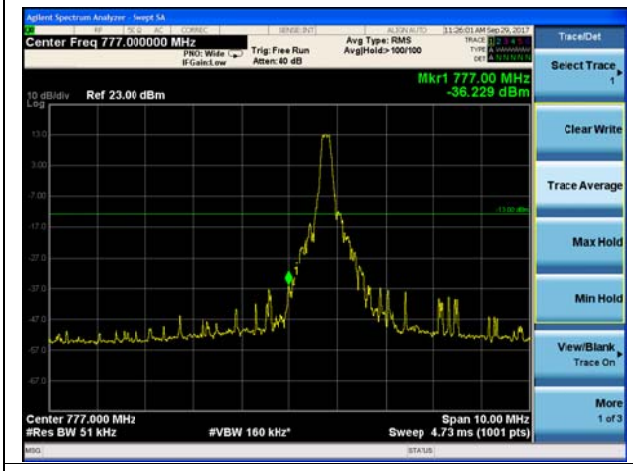
LTE Band 13 16QAM 5MHz CH-Low, 100%RB

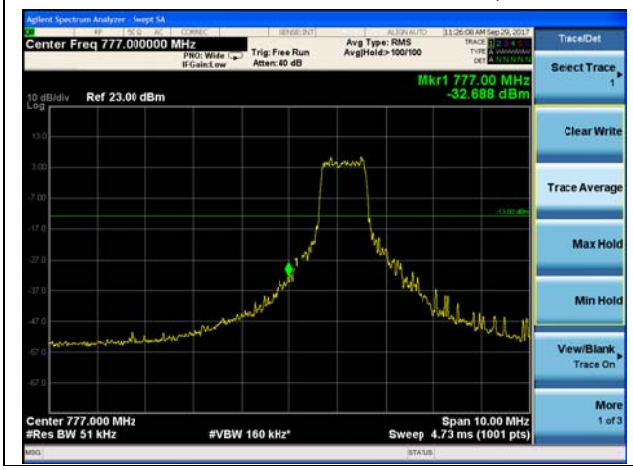
LTE Band 13 16QAM 5MHz CH-High, 100%RB

LTE Band 13 16QAM 10MHz CH-Low, 1 RB



LTE Band 13 16QAM 10MHz CH-High, 1 RB

LTE Band 13 16QAM 10MHz CH-Low, 100%RB



LTE Band 13 16QAM 10MHz CH-High, 100%RB

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5.5 Peak-to-Average Power Ratio (PAPR)

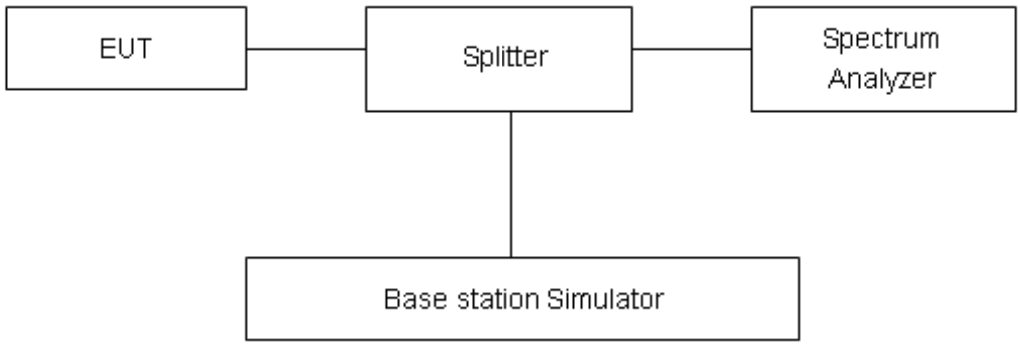
Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Methods of Measurement

Measure the total peak power and record as PPk. And measure the total average power and record as PAvg. Both the peak and average power levels must be expressed in the same logarithmic units (*e.g.*, dBm). Determine the PAPR from:
PAPR (dB) = PPk (dBm) - PAvg (dBm).

Test Setup



Limits

Rule Part 27.50(d)(5) Equipment employed must be authorized in accordance with the provisions of 24.51. Power measurements for transmissions by stations authorized under this section may be made either in accordance with a Commission-approved average power technique or in compliance with paragraph (d)(6) of this section. In measuring transmissions in this band using an average power technique, the peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for thenormal distribution is with the coverage factor k = 2, U= 0.4 dB.

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Test Results

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	Peak-to-Average Power Ratio (PAPR)		
				Peak(dBm)	Avg(dBm)	PAPR(dB)
Band4	1.4MHz	QPSK	20175/1732.5	33.37	22.09	11.28
		16QAM	20175/1732.5	34.13	22.03	12.10
	3MHz	QPSK	20175/1732.5	33.56	22.13	11.43
		16QAM	20175/1732.5	33.94	22.07	11.87
	5MHz	QPSK	20175/1732.5	32.06	22.12	9.94
		16QAM	20175/1732.5	32.62	22.03	10.59
	10MHz	QPSK	20175/1732.5	31.69	22.14	9.55
		16QAM	20175/1732.5	32.14	22.08	10.06
	15MHz	QPSK	20175/1732.5	30.77	22.10	8.67
		16QAM	20175/1732.5	30.68	22.03	8.65
	20MHz	QPSK	20175/1732.5	30.92	22.05	8.87
		16QAM	20175/1732.5	31.17	21.99	9.18

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	Peak-to-Average Power Ratio (PAPR)		
				Peak(dBm)	Avg(dBm)	PAPR(dB)
Band12	1.4MHz	QPSK	23095/707.5	32.63	22.66	9.97
		16QAM	23095/707.5	34.21	22.90	11.31
	3MHz	QPSK	23095/707.5	32.56	22.68	9.88
		16QAM	23095/707.5	33.51	22.95	10.56
	5MHz	QPSK	23095/707.5	32.27	22.64	9.63
		16QAM	23095/707.5	33.75	22.90	10.85
	10MHz	QPSK	23095/707.5	31.88	22.59	9.29
		16QAM	23095/707.5	32.03	22.86	9.17

Mode	Bandwidth	Modulation	Channel/ Frequency(MHz)	Peak-to-Average Power Ratio (PAPR)		
				Peak(dBm)	Avg(dBm)	PAPR(dB)
Band13	5MHz	QPSK	23230/782	32.64	22.68	9.96
		16QAM	23230/782	32.23	22.19	10.04
	10MHz	QPSK	23230/782	32.46	22.77	9.69
		16QAM	23230/782	32.68	22.95	9.73

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5.6 Frequency Stability

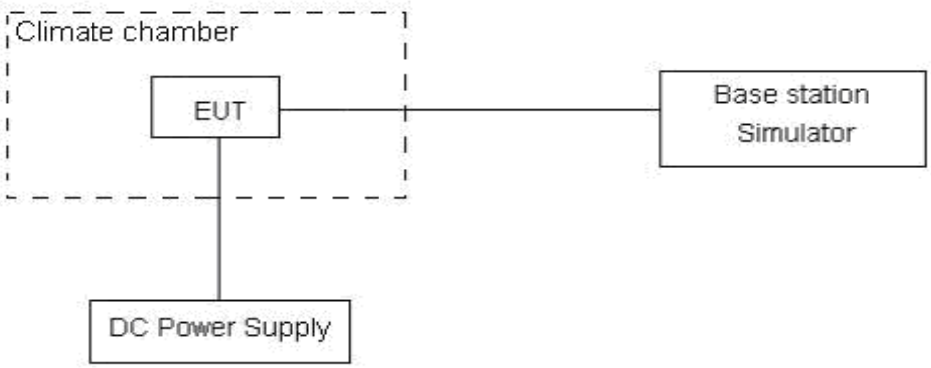
Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Method of Measurement

1. Frequency Stability (Temperature Variation)
   The temperature inside the climate chamber is varied from -40°C to +85°C in 10°C step size.
   (1)With all power removed, the temperature was decreased to -10°C and permitted to stabilize for three hours.
   (2)Measure the carrier frequency with the test equipment in a “call mode”. These measurements should be made within 1 minute of powering up the mobile station, to prevent significant self warming.
   (3) Repeat the above measurements at 10°C increments from -40°C to +85°C. Allow at least 1.5 hours at each temperature, un-powered, before making measurements.
2. Frequency Stability (Voltage Variation)
   The frequency stability shall be measured with variation of primary supply voltage as follows:
   (1) Vary primary supply voltage from 85 to 115 percent of the nominal value for other than hand carried battery equipment.
   (2) For hand carried, battery powered equipment, reduce primary supply voltage to the battery-operating end point which shall be specified by the manufacturer.
   This transceiver is specified to operate with an input voltage of between 3.3 V and 4.3 V, with a nominal voltage of 3.8V.

Test setup



Limits

No specific frequency stability requirements in part 27.54

Measurement Uncertainty

The assessed measurement uncertainty to ensure 99.75% confidence level for the normal distribution is with the coverage factor k = 3,U=0.01ppm.

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Test Result

Bandwidth	Test status	LTE Band 4 Channel 20175 Test Results (ppm)	
		QPSK	16QAM
1.4MHz	-40°C/Normal Voltage	-0.00444	-0.01766
	-30°C/Normal Voltage	-0.00386	-0.01513
	-20°C/Normal Voltage	-0.00514	-0.02027
	-10°C/Normal Voltage	-0.00174	-0.01773
	0°C/Normal Voltage	-0.00164	-0.01986
	10°C/Normal Voltage	-0.00239	-0.00601
	20°C/Normal Voltage	0.00020	-0.00454
	30°C/Normal Voltage	-0.00166	-0.00570
	40°C/Normal Voltage	-0.00035	-0.00673
	50°C/Normal Voltage	0.00115	-0.01853
	60°C/Normal Voltage	-0.00061	-0.00405
	70°C/Normal Voltage	-0.00411	-0.01242
	80°C/Normal Voltage	-0.00212	-0.02252
	85°C/Normal Voltage	-0.00124	-0.00496
	20°C/Min Voltage	-0.00300	-0.00576
	20°C/Max Voltage	-0.00315	-0.00454
3MHz	-40°C/Normal Voltage	-0.00127	-0.00275
	-30°C/Normal Voltage	-0.00184	-0.00448
	-20°C/Normal Voltage	0.00117	0.01527
	-10°C/Normal Voltage	0.00008	0.01465
	0°C/Normal Voltage	-0.00119	-0.00583
	10°C/Normal Voltage	-0.00255	-0.01694
	20°C/Normal Voltage	-0.00071	-0.00506
	30°C/Normal Voltage	-0.00063	-0.00412
	40°C/Normal Voltage	-0.00178	-0.00533
	50°C/Normal Voltage	-0.00078	-0.00294
	60°C/Normal Voltage	-0.00163	-0.01732
	70°C/Normal Voltage	-0.00091	0.01451
	80°C/Normal Voltage	-0.00111	-0.00443
	85°C/Normal Voltage	0.00137	-0.00253
	20°C/Min Voltage	0.00068	-0.00301
	20°C/Max Voltage	-0.00234	-0.00293
5MHz	-40°C/Normal Voltage	0.00119	-0.00739
	-30°C/Normal Voltage	0.00248	-0.00478
	-20°C/Normal Voltage	0.00018	-0.00477
	-10°C/Normal Voltage	-0.00357	0.00540

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	0°C/Normal Voltage	0.00002	-0.00554
	10°C/Normal Voltage	0.00259	-0.00377
	20°C/Normal Voltage	-0.00129	-0.00622
	30°C/Normal Voltage	-0.00012	-0.00676
	40°C/Normal Voltage	0.00036	0.00380
	50°C/Normal Voltage	-0.00119	-0.00579
	60°C/Normal Voltage	-0.00008	-0.00890
	70°C/Normal Voltage	-0.00115	-0.00618
	80°C/Normal Voltage	-0.00023	-0.00478
	85°C/Normal Voltage	-0.00179	-0.00302
	20°C/Min Voltage	-0.00188	0.00584
	20°C/Max Voltage	-0.00266	0.00141
10MHz	-40°C/Normal Voltage	0.00069	0.00372
	-30°C/Normal Voltage	0.00066	0.00297
	-20°C/Normal Voltage	-0.00119	0.01093
	-10°C/Normal Voltage	-0.00178	0.00982
	0°C/Normal Voltage	0.00127	0.00394
	10°C/Normal Voltage	0.00330	0.00301
	20°C/Normal Voltage	0.00152	0.01114
	30°C/Normal Voltage	0.00156	0.00070
	40°C/Normal Voltage	0.00224	0.01124
	50°C/Normal Voltage	0.00122	0.00386
	60°C/Normal Voltage	-0.00124	0.00870
	70°C/Normal Voltage	-0.00087	0.01063
	80°C/Normal Voltage	-0.00141	0.00606
	85°C/Normal Voltage	-0.00106	0.00305
	20°C/Min Voltage	-0.00190	0.00424
	20°C/Max Voltage	-0.00160	0.01408
15MHz	-40°C/Normal Voltage	0.00057	-0.00057
	-30°C/Normal Voltage	-0.00003	0.00023
	-20°C/Normal Voltage	0.00023	0.00077
	-10°C/Normal Voltage	-0.00110	-0.00147
	0°C/Normal Voltage	0.00182	-0.00067
	10°C/Normal Voltage	-0.00091	0.00086
	20°C/Normal Voltage	0.00169	-0.00042
	30°C/Normal Voltage	0.00042	-0.00301
	40°C/Normal Voltage	-0.00143	-0.00330
	50°C/Normal Voltage	0.00126	-0.00059
	60°C/Normal Voltage	0.00121	-0.00017
	70°C/Normal Voltage	-0.00056	-0.00046

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	80°C/Normal Voltage	0.00105	0.00106
	85°C/Normal Voltage	0.00025	-0.00055
	20°C/Min Voltage	-0.00002	-0.00061
	20°C/Max Voltage	0.00123	-0.00216
20MHz	-40°C/Normal Voltage	-0.00081	-0.02835
	-30°C/Normal Voltage	-0.00053	-0.02789
	-20°C/Normal Voltage	-0.00130	-0.02891
	-10°C/Normal Voltage	0.00002	-0.02948
	0°C/Normal Voltage	-0.00100	-0.02863
	10°C/Normal Voltage	0.00290	-0.02879
	20°C/Normal Voltage	-0.00079	-0.02917
	30°C/Normal Voltage	-0.00088	-0.03142
	40°C/Normal Voltage	-0.00241	-0.03015
	50°C/Normal Voltage	0.00066	-0.02809
	60°C/Normal Voltage	0.00032	-0.02992
	70°C/Normal Voltage	-0.00111	-0.02986
	80°C/Normal Voltage	0.00077	-0.02887
	85°C/Normal Voltage	-0.00151	-0.03063
	20°C/Min Voltage	-0.00136	-0.02918
	20°C/Max Voltage	0.00297	-0.02678

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Bandwidth	Test status	LTE Band 12 Channel 23095 Test Results (ppm)	
		QPSK	16QAM
1.4M	-40°C/Normal Voltage	-0.00582	-0.00338
	-30°C/Normal Voltage	-0.00315	-0.01134
	-20°C/Normal Voltage	-0.00743	-0.00290
	-10°C/Normal Voltage	-0.01025	-0.00325
	0°C/Normal Voltage	-0.00144	-0.00519
	10°C/Normal Voltage	-0.00079	-0.00345
	20°C/Normal Voltage	-0.00287	-0.00647
	30°C/Normal Voltage	-0.00308	-0.00445
	40°C/Normal Voltage	-0.00445	-0.00366
	50°C/Normal Voltage	-0.00411	0.00037
	60°C/Normal Voltage	-0.00223	0.00114
	70°C/Normal Voltage	-0.00192	0.00225
	80°C/Normal Voltage	-0.00257	-0.00076
	85°C/Normal Voltage	-0.00143	-0.00016
	20°C/Min Voltage	0.00037	0.00018
	20°C/Max Voltage	-0.00075	-0.00814
3M	-40°C/Normal Voltage	-0.00160	-0.02580
	-30°C/Normal Voltage	-0.00225	-0.02440
	-20°C/Normal Voltage	-0.00334	-0.02595
	-10°C/Normal Voltage	-0.00411	-0.02786
	0°C/Normal Voltage	-0.00343	-0.02806
	10°C/Normal Voltage	-0.00035	-0.02717
	20°C/Normal Voltage	-0.00117	-0.03013
	30°C/Normal Voltage	-0.00107	-0.02297
	40°C/Normal Voltage	-0.00177	-0.02185
	50°C/Normal Voltage	0.00148	-0.03153
	60°C/Normal Voltage	-0.00040	-0.02669
	70°C/Normal Voltage	0.00119	-0.02451
	80°C/Normal Voltage	-0.00037	-0.02336
	85°C/Normal Voltage	-0.00083	-0.02500
	20°C/Min Voltage	-0.00392	-0.02601
	20°C/Max Voltage	-0.00034	-0.02301
5MHz	-40°C/Normal Voltage	-0.00300	-0.03608
	-30°C/Normal Voltage	-0.00358	-0.03801
	-20°C/Normal Voltage	-0.00165	-0.04188
	-10°C/Normal Voltage	-0.00182	-0.03238
	0°C/Normal Voltage	-0.00225	-0.02841

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	10°C/Normal Voltage	-0.00376	-0.04006
	20°C/Normal Voltage	-0.00023	-0.02157
	30°C/Normal Voltage	-0.00059	-0.01495
	40°C/Normal Voltage	-0.00177	-0.01673
	50°C/Normal Voltage	-0.00110	-0.02314
	60°C/Normal Voltage	-0.00414	-0.02293
	70°C/Normal Voltage	0.00170	-0.02475
	80°C/Normal Voltage	0.00024	-0.01739
	85°C/Normal Voltage	-0.00040	-0.02205
	20°C/Min Voltage	0.00365	-0.03228
	20°C/Max Voltage	-0.00274	-0.03902
10MHz	-40°C/Normal Voltage	-0.00411	0.00379
	-30°C/Normal Voltage	-0.00327	0.00582
	-20°C/Normal Voltage	-0.00362	-0.00310
	-10°C/Normal Voltage	-0.00174	-0.00280
	0°C/Normal Voltage	-0.00083	-0.00351
	10°C/Normal Voltage	-0.00202	0.00114
	20°C/Normal Voltage	-0.00194	0.00220
	30°C/Normal Voltage	-0.00016	-0.00488
	40°C/Normal Voltage	-0.00100	-0.00423
	50°C/Normal Voltage	-0.00232	0.00377
	60°C/Normal Voltage	-0.00271	-0.00411
	70°C/Normal Voltage	-0.00400	-0.00150
	80°C/Normal Voltage	0.00120	0.00522
	85°C/Normal Voltage	-0.00137	0.00083
	20°C/Min Voltage	0.00259	-0.00408
	20°C/Max Voltage	-0.00250	0.00533

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